
HA17301P

Quad Operational Amplifier

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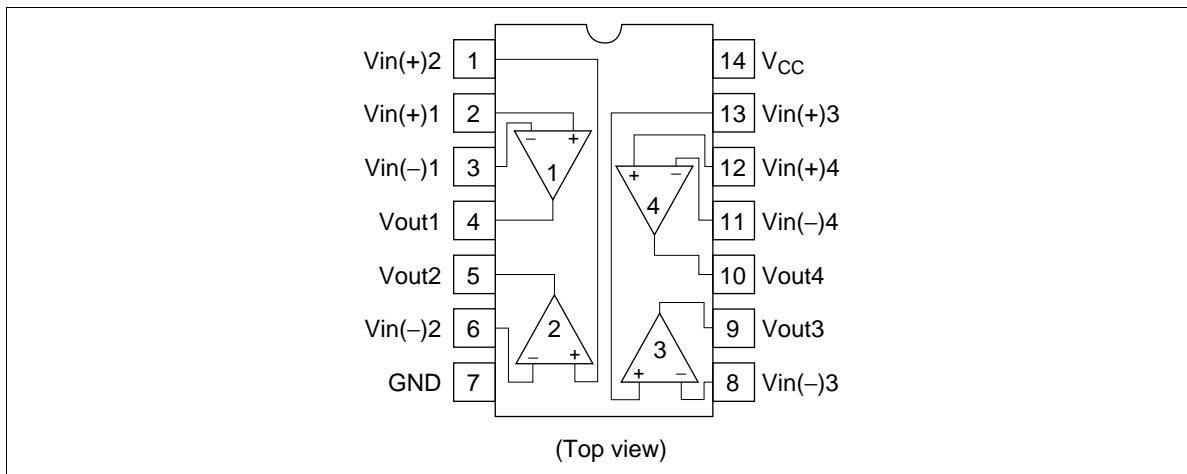
Description

The HA17301P is an internal-compensation quad operational amplifier that operates on a single-voltage power supply. Typical applications for the HA17301P include waveform generators, voltage regulators, logic circuits, and voltage-controlled oscillators.

Features

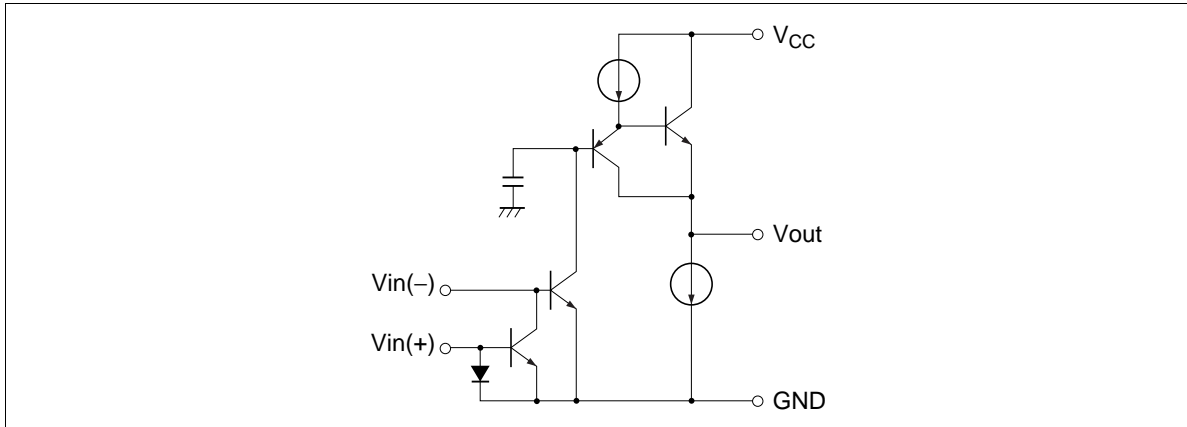
- Wide operating temperature range
- Single-voltage power supply operation
- Internal phase compensation
- Low input bias current

Pin Arrangement



HA17301P

Circuit Structure (1/4)



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Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Power-supply voltage	V _{CC}	28	V
Noninverting input current	I _r	5	mA
Sink current	I _{o sink}	50	mA
Source current	I _{o source}	50	mA
Allowable power dissipation*	P _T	625	mW
Operating temperature	T _{opr}	-20 to +75	°C
Storage temperature	T _{stg}	-55 to +125	°C

Note: This is the allowable value up to Ta = 50°C for the HA17301P. Derate by 8.3 mW/°C above that temperature.

Electrical Characteristics (V_{CC} = +15 V, R_L = 5.0 kΩ, Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Voltage gain	A _{VD}	1,000	1,400	—	V/V	
Supply current	I _{CO}	—	7.7	10	mA	Non inverting input open
	I _{CG}	—	8.3	14	mA	Non inverting input grounded
Input bias current	I _{IB}	—	80	300	nA	R _L = ∞
Current mirror gain	A _i	0.80	0.94	1.16	A/A	I _r = 200 μA
Output source current	I _{o source}	3	13	—	mA	V _{OH} = 0.4 V
		—	10	—	mA	V _{OH} = 9.0 V
Output sink current	I _{o sink}	0.5	0.75	—	mA	V _{OL} = 0.4 V
Output voltage	V _{OH}	13.5	13.9	—	V	
	V _{OL(inv)}	—	0.04	0.1	V	Inverting input driven
	V _{OL(non)}	—	0.55	—	V	Non inverting input driven
Input resistance	R _{in}	0.1	1.0	—	MΩ	Inverting input only
Slew rate	SR	—	0.2	—	V/μs	C _L = 100 pF, R _L = 5.0 kΩ
Bandwidth	BW	—	2.6	—	MHz	A _{VD} = 1
Phase margin	φ _m	—	87	—	deg	
Power-supply rejection ratio	PSRR	—	63	—	dB	f = 100 Hz
Channel separation	CS	—	63	—	dB	f = 1.0 kHz

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HA17301P Application Examples

The HA17301P is a quad operational amplifier, and consists of four operational amplifier circuits and one bias current circuit. The HA17301P features a wide operating temperature range, single-voltage power supply operation, internal phase compensation, a wide zero-cross bandwidth, a low input bias current, and a high open-loop gain. Thus the HA17301P can be used in a wide range of applications. This section describes several applications using the HA17301P.

HA17301 Circuit Operation

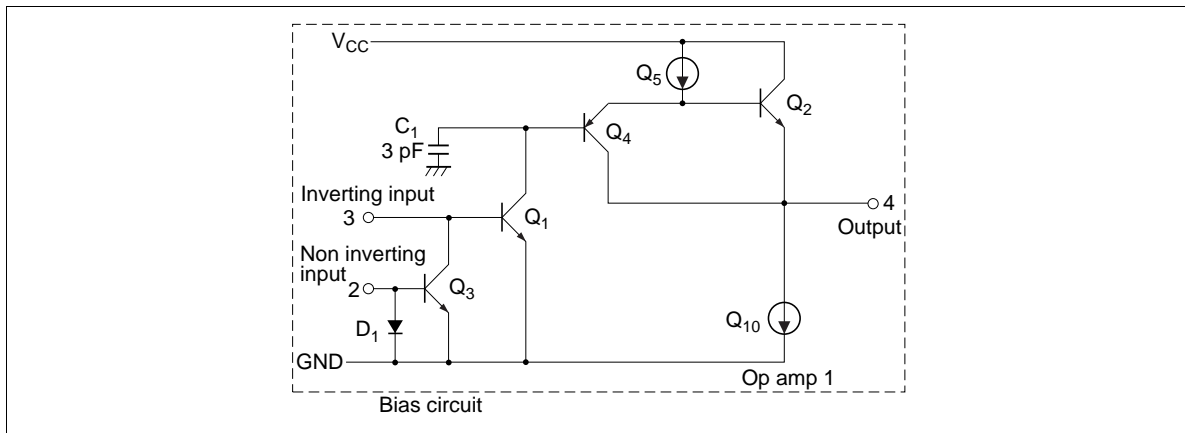


Figure 1 HA17301 Internal Equivalent Circuit

Figure 1 shows the internal equivalent circuit for the HA17301P bias circuit and one operational amplifier circuit (Op amp 1).

Op amp 1 is basically an emitter ground type operational amplifier in which the input transistor Q_1 , the buffer transistor Q_4 , the current source transistor Q_5 , the output emitter-follower transistor Q_2 , and the current source transistor Q_{10} form an inverting amplifier. The voltage gain of this circuit is all given by the transistor Q_1 , and the adoption of the current-supply load Q_5 allows this circuit to provide a large open-loop gain even at low power-supply voltages. Next, the emitter-follower transistor Q_2 lowers the output impedance of this circuit. The use of the power-supply transistor Q_{10} as the load for Q_2 gives this circuit an extremely large dynamic range, and essentially an amplitude from ground to $(V_{CC} - 1)$ can be acquired. Also, the buffer transistor Q_4 is used to reduce the input current without increasing the DC input voltage level. Since the capacitor C_1 is used to preserve stability when this inverting amplifier is used as a closed circuit, no external compensation is required.

Now consider the non inverting circuit. Assuming that the current amplification ratio provided by Q_3 is adequately large for the current flowing into the non inverting input, then all that current will flow through diode D_1 and the voltage drop induced in the diode D_1 by this input current will be applied to the Q_3 base-emitter junction. Therefore, if D_1 and Q_3 are matched, a current equal to the input current will flow in the Q_3 emitter. Assuming that the current amplification ratio provided by Q_3 is adequately large, a current equal to the input current will flow in the Q_3 collector. This is called a “current mirror”, and when an external feedback resistor is used, a current equal to the non inverting input current will flow in this resistor and thus determine the output voltage.

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Inverting Amplifier

There are three bias techniques for biasing the inverting amplifier, the single power supply bias technique, the NV_{BE} bias technique, and the load voltage bias technique.

1. Single Power Supply Bias Technique

Figure 2 shows a common AC amplifier that is biased by the same power supply as the supply that operates the amplifier.

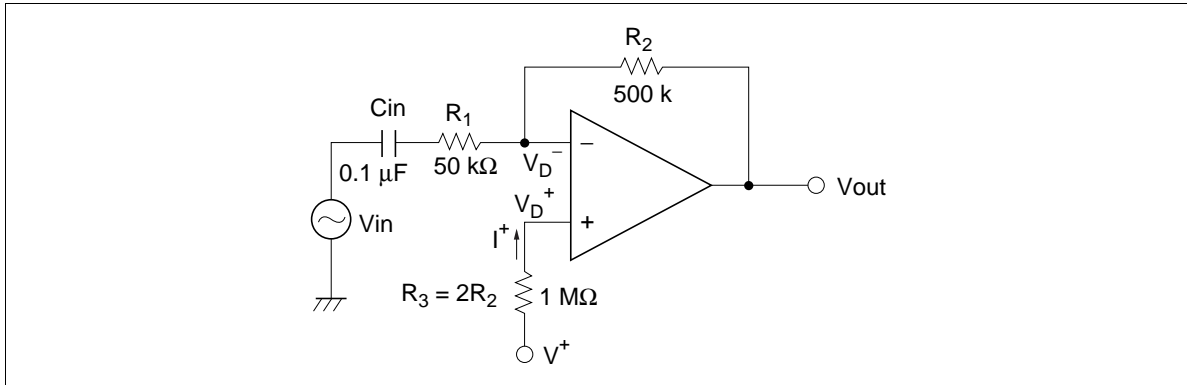


Figure 2 Single Power Supply Bias Technique

$$\frac{V_{out}}{V_{in}} = - \frac{R_2}{R_1} \quad (1)$$

2. NV_{BE} Bias Technique

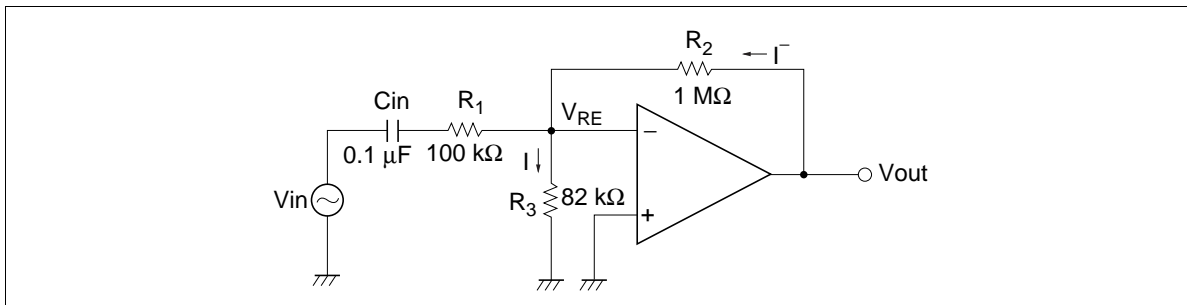


Figure 3 NV_{BE} Bias Technique

This is the most useful application of an inverting AC amplifier. In this circuit, the input bias voltage V_{BE} for the inverting input is determined by the current that flows to ground through the resistor R_3 .

$$\frac{V_{out}}{V_{in}} = - \frac{R_2}{R_1} \quad (2)$$

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Triangular Wave oscillator

Triangular waveforms are usually acquired by integrating an alternating positive and negative DC voltage. Figure 4 shows the relation between the input and output in this circuit.

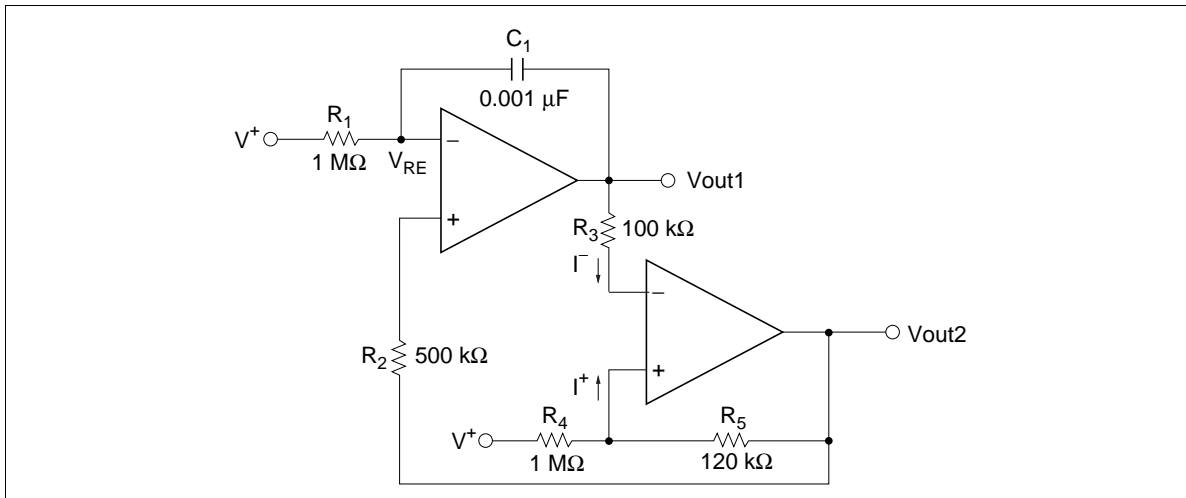


Figure 4 Triangular Wave Oscillator

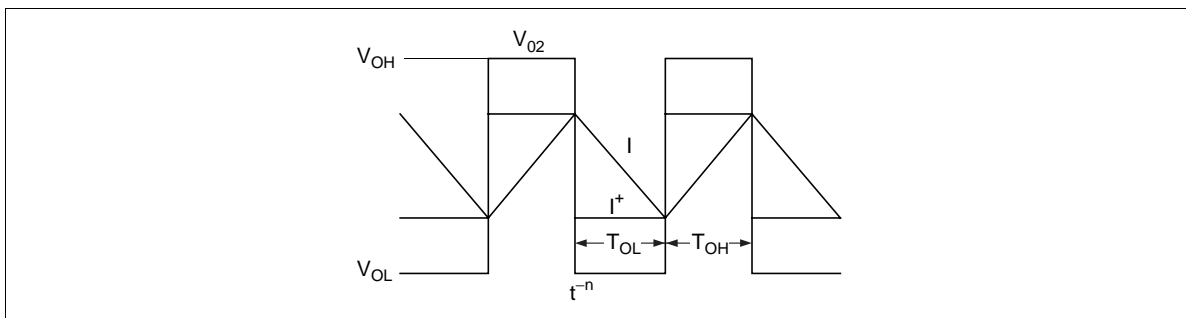


Figure 5 Triangular Wave Generator Operation

$$T_{OL} = \frac{C_1 R_1 R_3 V_{OH}}{R_5 (V^+ - V_{BE})} \quad (3)$$

$$T_{OH} = \frac{C_1 R_3 V^+}{R_5 \left(\frac{V_{OH}}{R_2} - \frac{V^+ - V_{BE}}{R_1} \right)} \quad (4)$$

Here, if $R_1 = 2 \cdot R_2$, $V_{OH} = V^+$, and $V^+ > V_{BE}$, then:

$$T_{OH} + T_{OL} = \frac{2C_1 R_1 R_3}{R_5} \quad (5)$$

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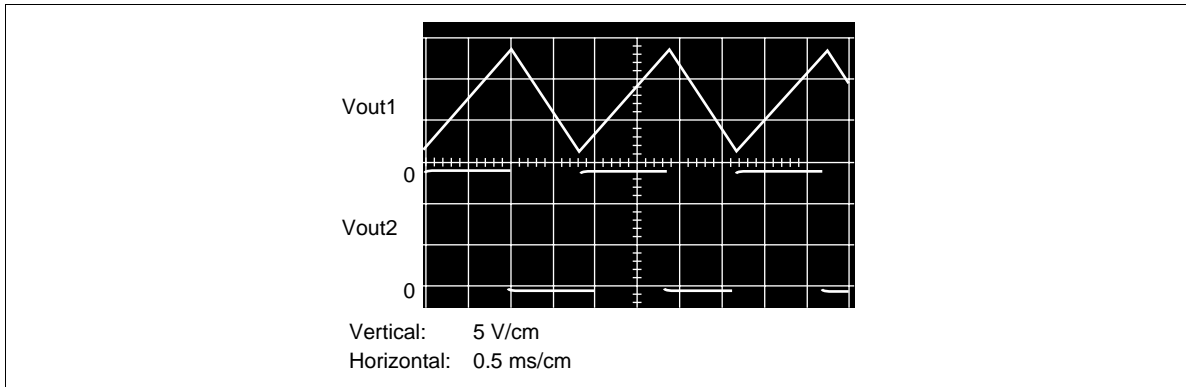


Figure 6 Triangular Wave Generator Operating Waveform

Table 1

Test Item		Tested Value	Calculated Value	Unit	Test Condition
Triangular wave generator	T_{OH}	1.06	0.83	ms	$V_{CC} = 15\text{ V}$, $V^+ = 15\text{ V}$, $C_1 = 0.001\text{ }\mu\text{F}$, $R_1 = 1\text{ M}\Omega$, $R_2 = 500\text{ k}\Omega$, $R_3 = 100\text{ k}\Omega$, $R_4 = 1\text{ M}\Omega$, $R_5 = 120\text{ k}\Omega$ Figure 4
	T_{OL}	0.82	0.83	ms	
	V_{OIH}	13.5	14	V	
	V_{OIL}	1.5	1.5	V	

Comparators

This section describes three comparator circuits implemented using the HA17301P, a positive input voltage comparator, a negative input voltage comparator, and a power voltage comparator.

1. Positive Input Voltage Comparator

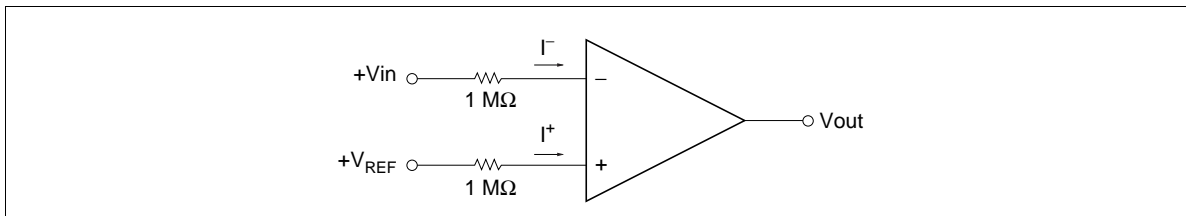


Figure 7 Positive Input Voltage Comparator

V_{out} in the circuit shown in figure 7 will be V_{OH} when $I^- < I^+$ and V_{OL} when $I^- > I^+$. To assure that this circuit operates correctly, the reference voltage must be greater than V_{BE} .

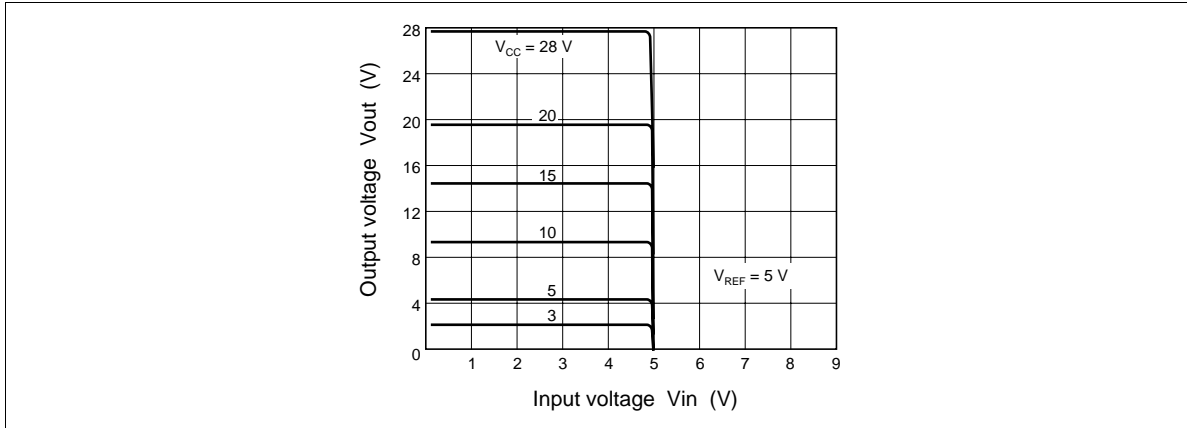


Figure 8 Positive Input Voltage Comparator Operating Characteristics (1)

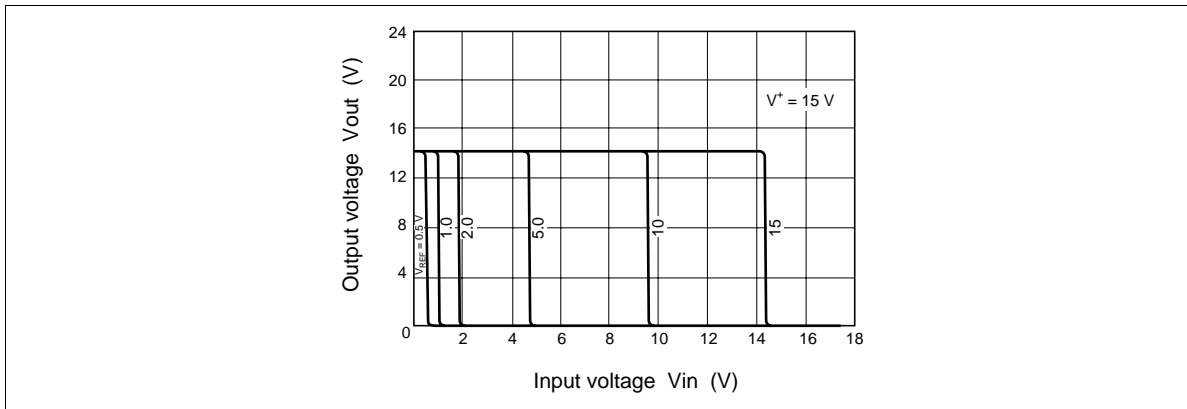


Figure 9 Positive Input Voltage Comparator Operating Characteristics (2)

2. Negative Input Voltage Comparator

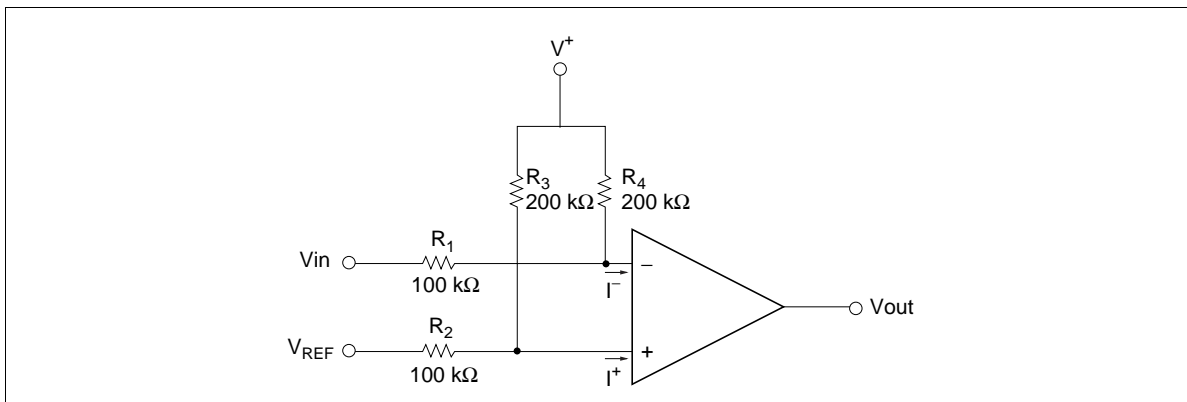


Figure 10 Negative Input Voltage Comparator

$$V_{IN} > R_1 \left\{ V_{BE} \left(\frac{1}{R_1} + \frac{1}{R_4} \right) - \frac{V^+}{R_4} \right\} \quad (6)$$

If resistor R_4 is chosen so that formula 6 holds, and

$$V_{REF} > R_2 \left\{ V_{BE} \left(\frac{1}{R_2} + \frac{1}{R_3} \right) - \frac{V^+}{R_3} \right\} \quad (7)$$

if resistor R_4 is chosen so that formula 7 holds, then even if V_{IN} and V_{REF} are negative, V_{out} will be V_{OH} when $I^- < I^+$ and V_{OL} when $I^- > I^+$, as was the case for the positive input voltage comparator.

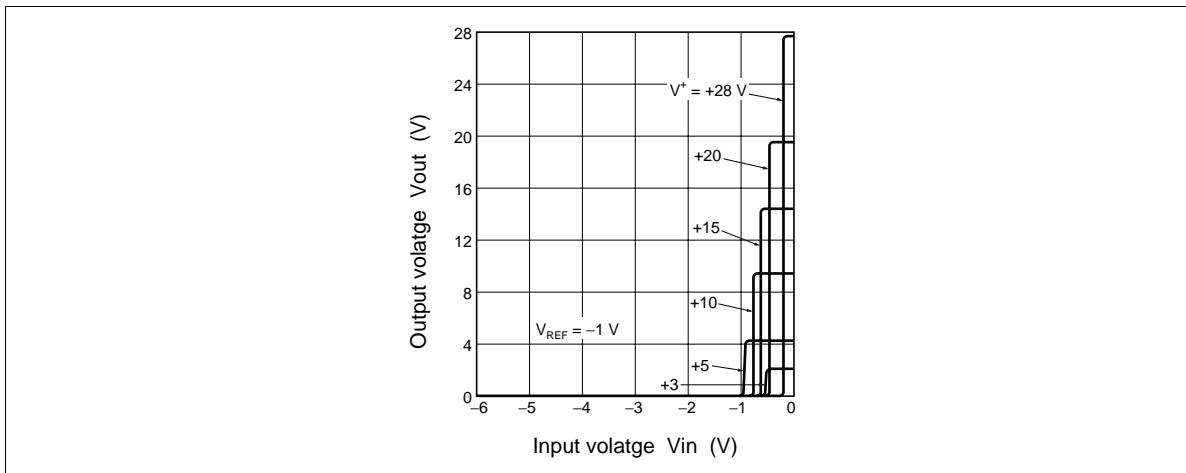


Figure 11 Negative Input Voltage Comparator Operating Characteristics (1)

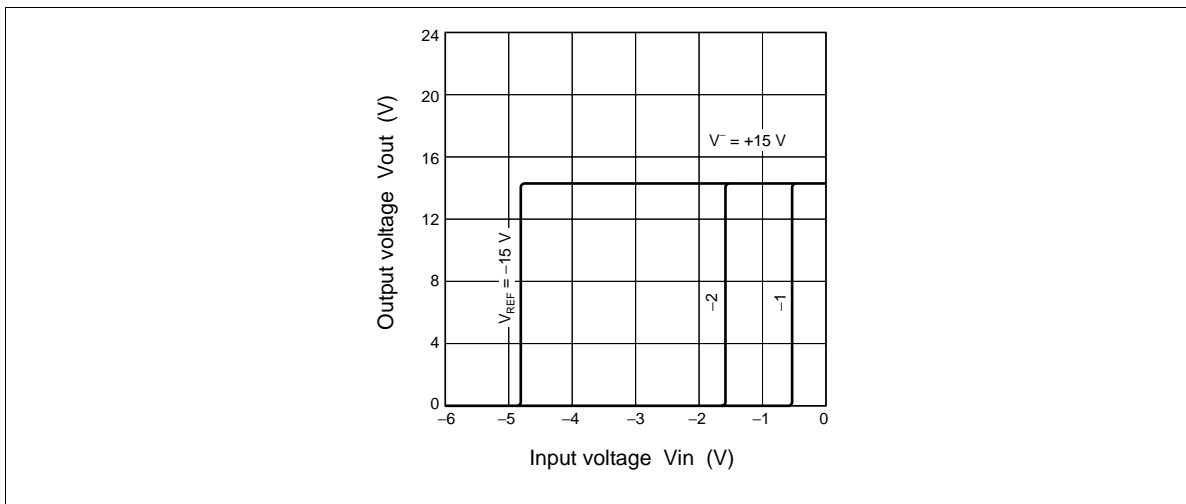


Figure 12 Negative Input Voltage Comparator Operating Characteristics (2)

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3. Power Comparator

As shown in figure 13, adding an external transistor allows the circuit to drive loads that require a larger current than the output current that the HA17301P can supply.

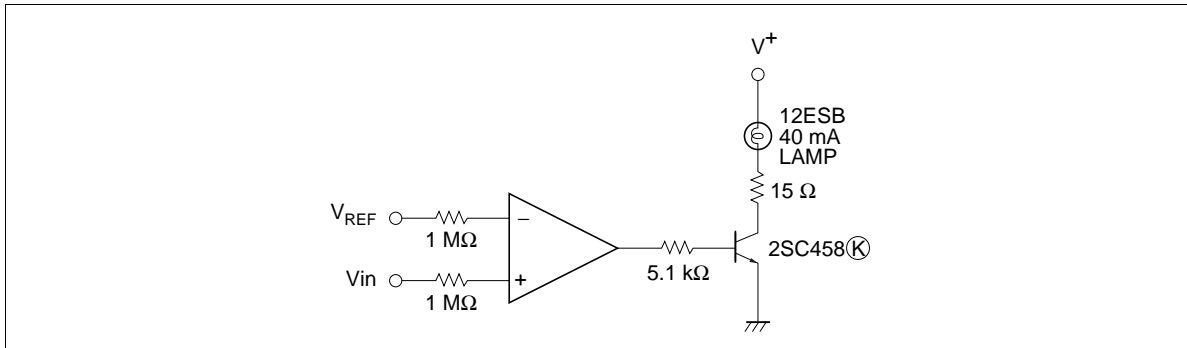


Figure 13 Power Comparator

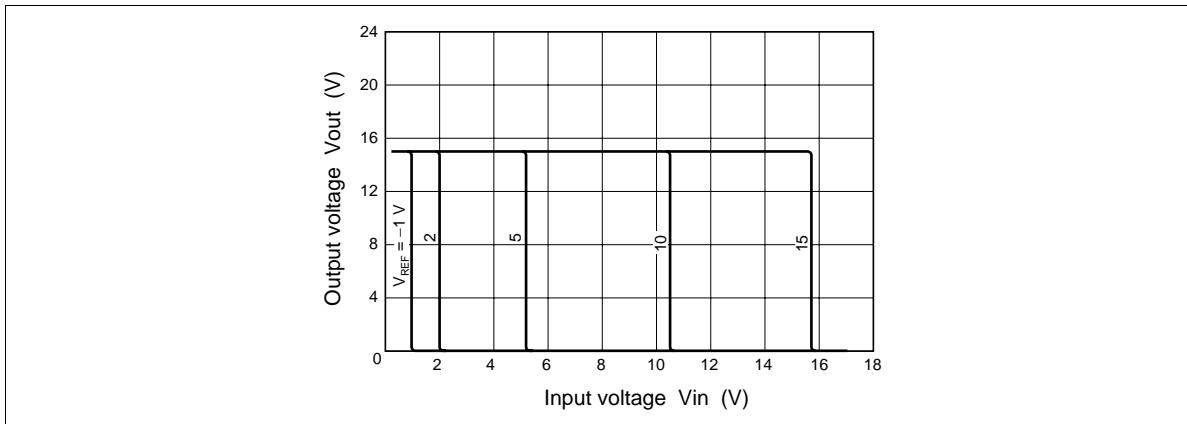
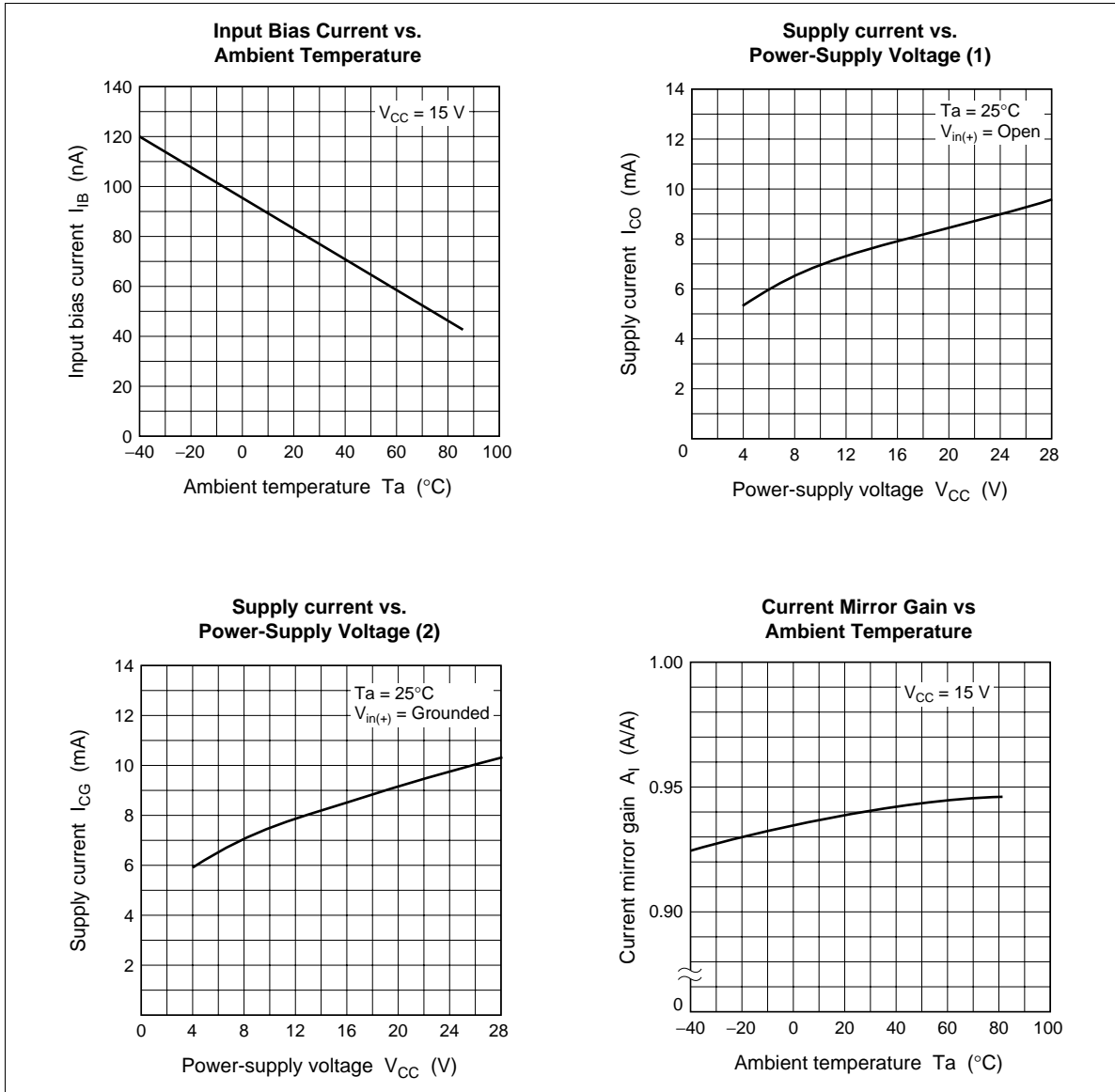


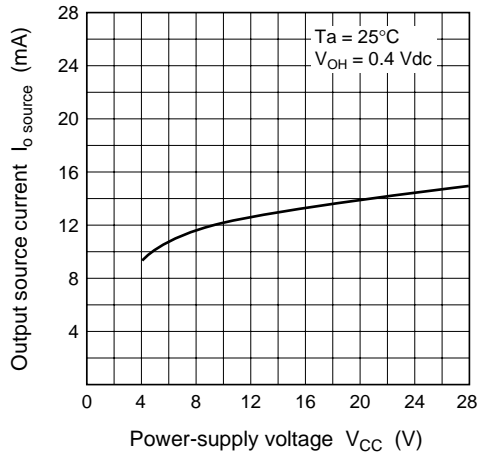
Figure 14 Power Comparator Operating Characteristics

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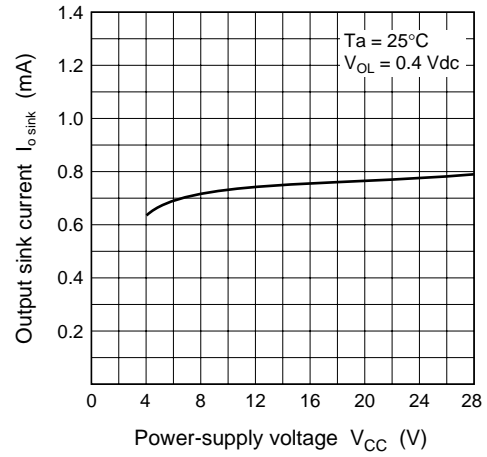
Characteristic Curves



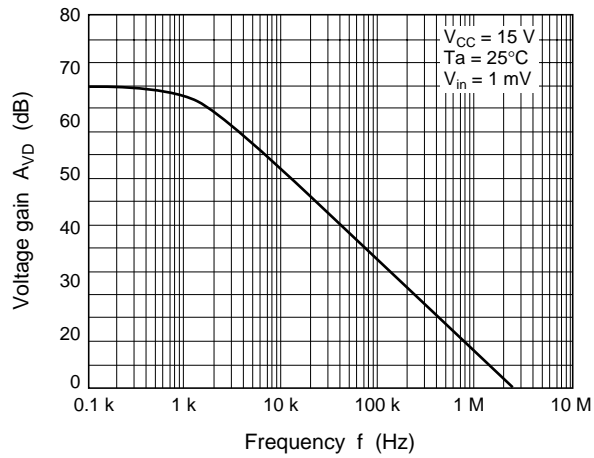
Output Source Current vs. Power-Supply Voltage



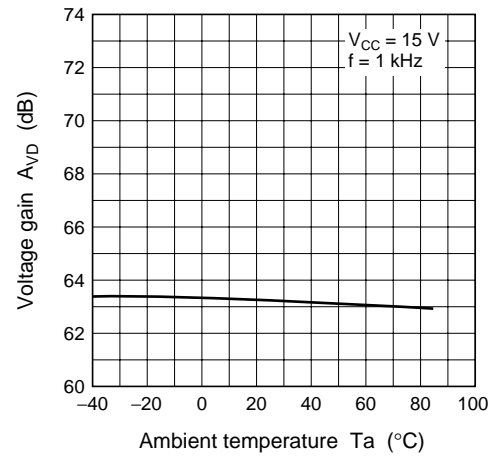
Output Sink Current vs. Power-Supply Voltage



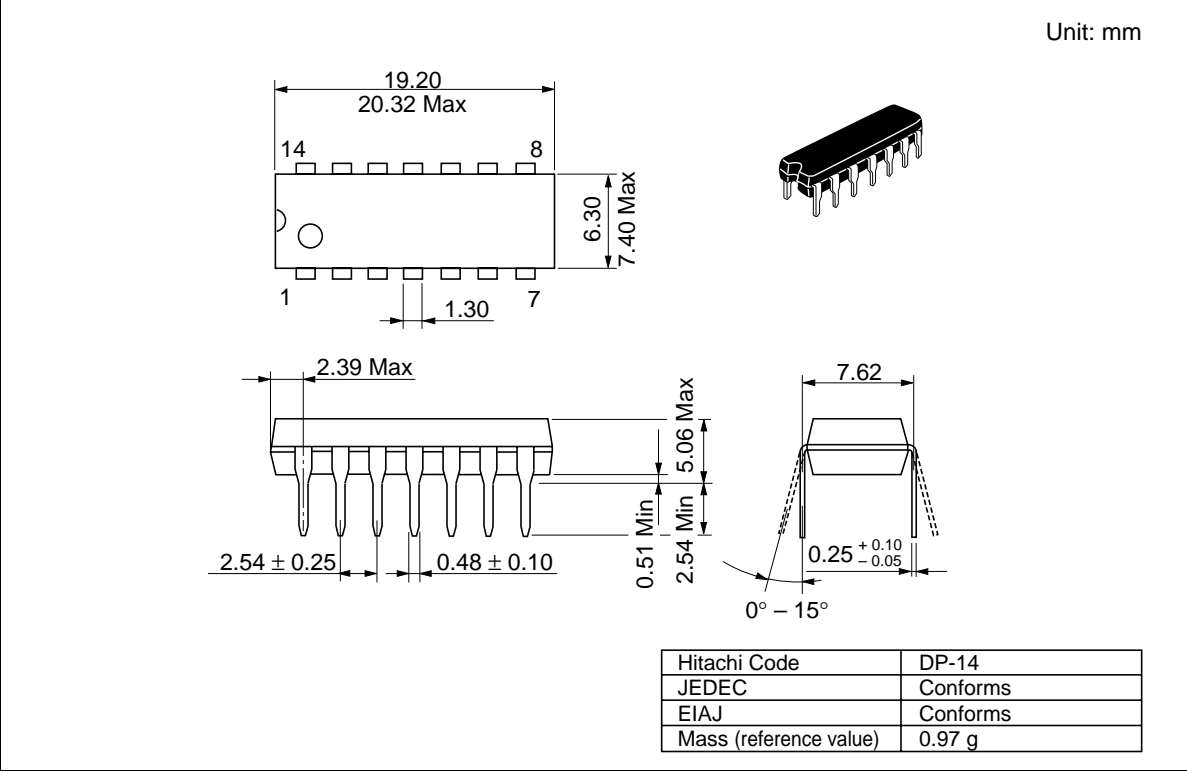
Voltage Gain vs. Frequency



Voltage Gain vs. Ambient Temperature



Package Dimensions



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